TOSHIBA Photocoupler GaAs IRED & Photo-Transistor

TLP627,TLP627-2,TLP627-4

Programmable Controllers **DC-output Module** Telecommunication

The TOSHIBA TLP627,-2 and -4 consists of a gallium arsenide infrared emitting diode optically coupled to a darlington connected phototransistor which has an integral base-emitter resistor to optimize switching speed and elevated temperature characteristics.

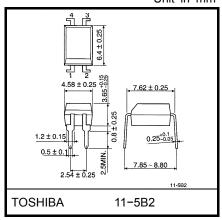
The TLP627-2 offers two isolated channels in a eight lead plastic DIP, while the TLP627-4 provide four isolated channels per package.

Collector-Emitter Voltage Current Transfer Ratio

Isolation Voltage

UL Recognized

- : 300V(Min)
- : 1000%(Min) : 5000Vrms(Min)
- : UL1577, File No.E67349



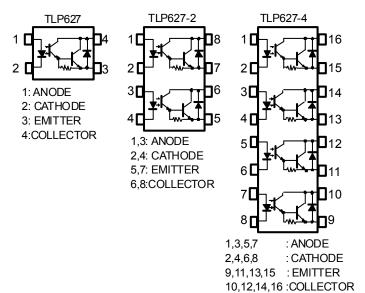
Weight: 0.26 g (typ.)

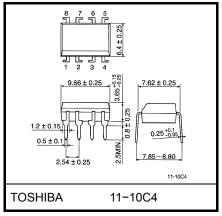
	Made in Ja	ban	Made in Thailand		
UL Recognized	E67349	*1	E152349	*1	
BSI Approved	7426, 7427	*2	7426, 7427	*2	

*1 UL1577

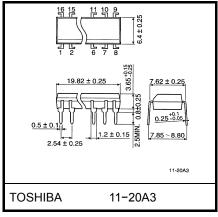
*2 BS EN60065: 2002, BS EN60950-1: 2002

Pin Configuration (top view)





Weight: 0.54 g (typ.)



Weight: 1.1 g (typ.)

Absolute Maximum Ratings (Ta=25°C)

Characteristics			Ra		
	Characteristics	Symbol	TLP627 TLP627-2 TLP627-4		Unit
	Forward Current	I _F	60	50	mA
	Forward Current Derating	$\Delta I_F /°C$	−0.7(Ta≥39°C)	−0.5(Ta≥25°C)	mA /°C
	Pulse Forward Current	I _{FP}	1(100µs pu	А	
LED	Power Dissipation (1 Circuit)	PD	100	70	mW
	Power Dissipation Derating (Ta≥25°C,1 Circuit)	$\Delta P_D /°C$	-1.0	-0.7	mW /°C
	Reverse Voltage	V _R		5	V
	Junction Temperature	Tj	1:	25	°C
	Collector-Emitter Voltage	V _{CEO}	30	00	V
	Emitter -Collector Voltage	V _{ECO}	0	.3	V
Detector	Collector Current	Ic	1:	50	mA
Dete	Collector Power Dissipation (1 Circuit)	Pc	150(*300)	100	mW
	Collector Power Dissipation Derating (Ta≥25°C,1 Circuit)	$\Delta P_{c} / C$	-1.5(*-3.5)	-1.0	mW /°C
	Junction Temperature	Tj	125		°C
Оре	erating Temperature Range	T _{opr}	-55	~100	°C
Sto	rage Temperature Range	T _{stg}	-55	~125	°C
Lea	d Soldering Temperature (10s)	T _{sold}	260(1	Osec)	°C
Tota	al Package Power Dissipation	PT	250(*320)	150	mW
Tota	al Package Power Dissipation Derating (Ta≥25°C,1 Circuit)	$\Delta P_T/°C$	-2.5(*-3.2)	-1.5	mW /°C
Isol	ation Voltage (AC,1min., R.H.≤60%) (Note1)	BVs	50	00	Vrms
			*IF=20mA M	21/	

*IF=20mA Max

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

(Note1)Device considered a two terminal device : LED side pins Shorted together and DETECTOR side pins shorted together.

Recommended Operating Conditions

Characteristics	Symbol	Min.	Тур.	Max.	Unit
Supply Voltage	V _{cc}	_	_	200	V
Forward Current	I _F	_	16	25	mA
Collector Current	Ι _c	_	_	120	mA
Operating Temperature	T _{opr}	-25		85	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

Individual Electrical Characteristics (Ta=25°C)

	Characteristics	Symbol	mbol Test Condition		Тур.	Max.	Unit
	Forward Voltage	V _F	V _F I _F = 10 mA		1.15	1.3	V
LED	Reverse Current	I _R			_	10	μA
	Capacitance	Ст			30	_	pF
	Collector-Emitter Breakdown Voltage	V _{(BR)CEO}	V _{(BR)CEO} IC = 0.1mA		_	l	V
tor	Emitter-Collector Breakdown Voltage	V _{(BR)ECO}	IE = 0.1mA	0.3	_		V
Detector			V _{CE} = 200V		10	200	nA
	Collector Dark Current I_{CEO} $V_{CE} = 200V$, Ta = 85°C		V _{CE} = 200V , Ta = 85°C	_	_	20	μA
	Capacitance Collector to Emitter	C _{CE}	V=0 , f=1MHz		10		pF

Coupled Electrical Characteristics (Ta=25°C)

Characteristics	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Current Transfer Ratio	I_{C}/I_{F}	I _F =1mA , V _{CE} =1V	1000	4000	_	%
Saturated CTR	I _C /I _F (sat)	I_F =10mA , V_{CE} =1V	500	—	—	%
Collector-Emitter	V _{CF} (sat)	I _C =10mA , I _F =1mA	-	—	1.0	V
Saturation Voltage	v _{CE} (Sal)	I _C =100mA , I _F =10mA	0.3	-	1.2	v

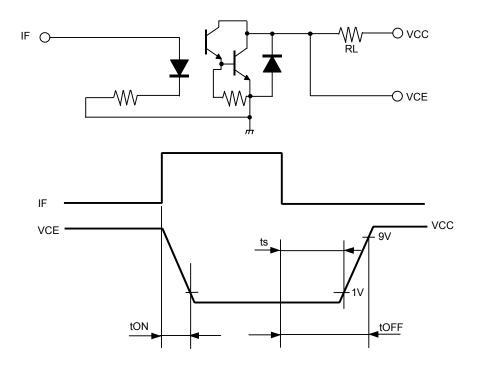
Isolation Electrical Characteristics (Ta=25°C)

Characteristics	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Capacitance Input to Output	Cs	V _S =0 , f=1MHz	_	0.8	_	pF
Isolation Resistance	Rs	V _S =500V , R.H.≤60%	5×10 ¹⁰	10 ¹⁴	_	Ω
Isolation Voltage		AC, 1minute	5000	_	_	Vrms
	BVs	AC, 1second, in oil	_	10000	_	VIIIS
		DC, 1 minute, in oil	_	10000		Vdc

Switching Characteristics (Ta=25°C)

Characteristics	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Rise Time	tr	N/ 40V/	—	40	—	
Fall Time	tf	V _{cc} =10V I _c =10mA		15	—	
Turn-on Time	ton	$R_L = 100\Omega$		50	—	
Turn-off Time	toff			15		μs
Turn-on Time	tON	R _L =180Ω (Fig.1) V _{CC} =10V , I _F =16mA		5	-	
Strage Time	ts			40	_	
Turn-off Time	tOFF			80		

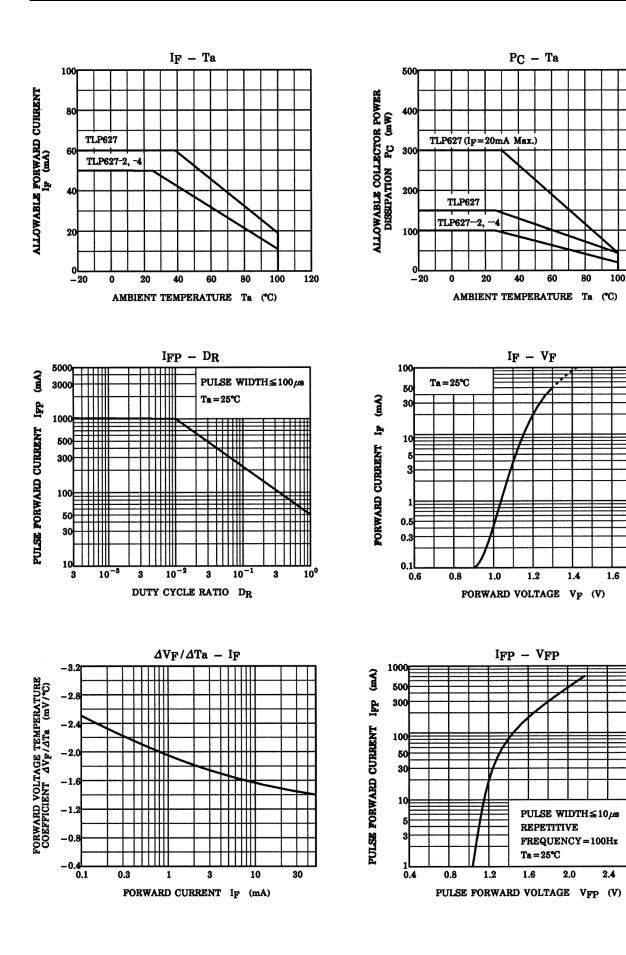
Fig.1 Switching Time Test Circuit



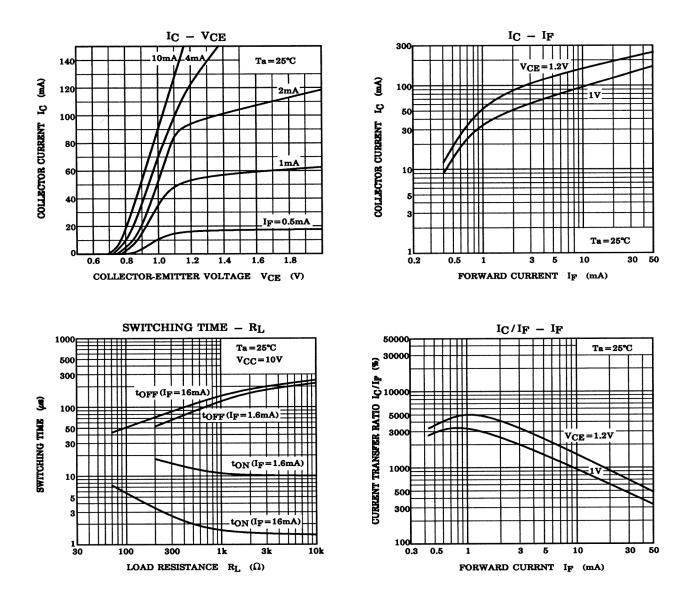
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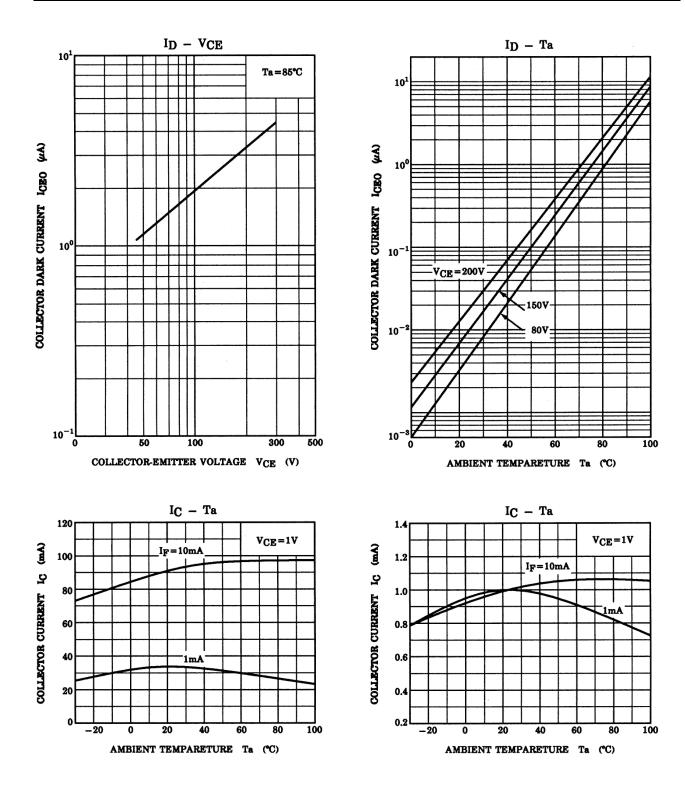
120

1.8



2.8





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